

N-Channel 40-V (D-S) MOSFET

Key Features:

- Low $r_{DS(on)}$ trench technology
- Low thermal impedance
- Fast switching speed

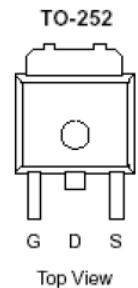
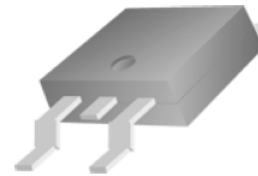
Typical Applications:

- White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

| PRODUCT SUMMARY | | |
|-----------------|----------------------------|-----------|
| V_{DS} (V) | $r_{DS(on)}$ (m Ω) | I_D (A) |
| 40 | 32 @ $V_{GS} = 10V$ | 33 |
| | 42 @ $V_{GS} = 4.5V$ | 29 |



RoHS
COMPLIANT
HALOGEN
FREE



| ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED) | | | | |
|---|--------------------------|----------------|------------|------------------|
| Parameter | | Symbol | Limit | Units |
| Drain-Source Voltage | | V_{DS} | 40 | V |
| Gate-Source Voltage | | V_{GS} | ± 20 | |
| Continuous Drain Current ^a | $T_A = 25^\circ\text{C}$ | I_D | 33 | A |
| Pulsed Drain Current ^b | | I_{DM} | 50 | |
| Continuous Source Current (Diode Conduction) ^a | | I_S | 35 | A |
| Power Dissipation ^a | $T_A = 25^\circ\text{C}$ | P_D | 50 | W |
| Operating Junction and Storage Temperature Range | | T_J, T_{stg} | -55 to 175 | $^\circ\text{C}$ |

| THERMAL RESISTANCE RATINGS | | | |
|--|-----------------|---------|--------------------|
| Parameter | Symbol | Maximum | Units |
| Maximum Junction-to-Ambient ^a | $R_{\theta JA}$ | 40 | $^\circ\text{C/W}$ |
| Maximum Junction-to-Case | $R_{\theta JC}$ | 3 | |

Notes

- Surface Mounted on 1" x 1" FR4 Board.
- Pulse width limited by maximum junction temperature

Electrical Characteristics

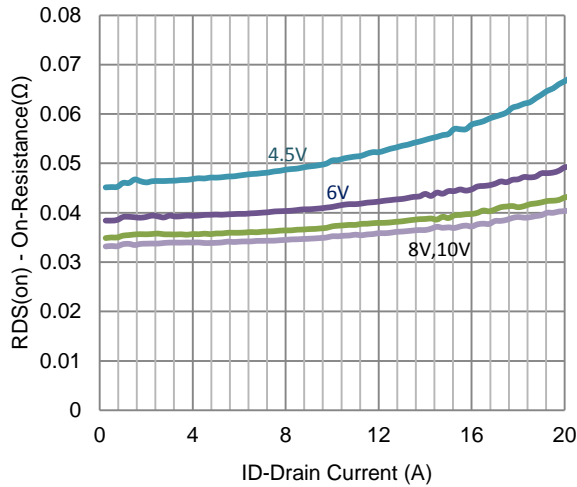
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|---------------------------------|--------------|---|-----|------|-----------|------------|
| Static | | | | | | |
| Gate-Source Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = 250 \mu A$ | 1 | | | V |
| Gate-Body Leakage | I_{GSS} | $V_{DS} = 0 V, V_{GS} = \pm 20 V$ | | | ± 100 | nA |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 32 V, V_{GS} = 0 V$ | | | 1 | uA |
| | | $V_{DS} = 32 V, V_{GS} = 0 V, T_J = 55^\circ C$ | | | 25 | |
| On-State Drain Current | $I_{D(on)}$ | $V_{DS} = 5 V, V_{GS} = 10 V$ | 33 | | | A |
| Drain-Source On-Resistance | $r_{DS(on)}$ | $V_{GS} = 10 V, I_D = 20 A$ | | | 32 | m Ω |
| | | $V_{GS} = 4.5 V, I_D = 18 A$ | | | 40 | |
| Forward Transconductance | g_{fs} | $V_{DS} = 15 V, I_D = 20 A$ | | 10 | | S |
| Diode Forward Voltage | V_{SD} | $I_S = 17.6 A, V_{GS} = 0 V$ | | 1.15 | | V |
| Dynamic | | | | | | |
| Total Gate Charge | Q_g | $V_{DS} = 20 V, V_{GS} = 5.5 V,$ $I_D = 20 A$ | | 3 | | nC |
| Gate-Source Charge | Q_{gs} | | | 1.7 | | |
| Gate-Drain Charge | Q_{gd} | | | 1.0 | | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DS} = 20 V, R_L = 1 \Omega,$ $I_D = 20 A,$ $V_{GEN} = 10 V, R_{GEN} = 6 \Omega$ | | 2 | | ns |
| Rise Time | t_r | | | 4 | | |
| Turn-Off Delay Time | $t_{d(off)}$ | | | 10 | | |
| Fall Time | t_f | | | 4 | | |
| Input Capacitance | C_{iss} | $V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz$ | | 186 | | pF |
| Output Capacitance | C_{oss} | | | 40 | | |
| Reverse Transfer Capacitance | C_{rss} | | | 25 | | |

Notes

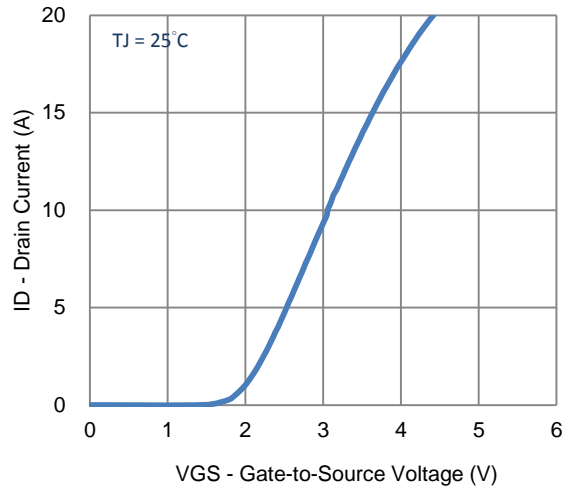
- Pulse test: PW \leq 300us duty cycle \leq 2%.
- Guaranteed by design, not subject to production testing.

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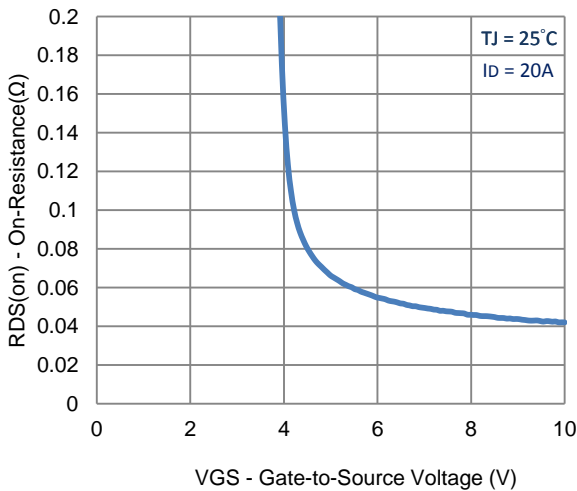
Typical Electrical Characteristics



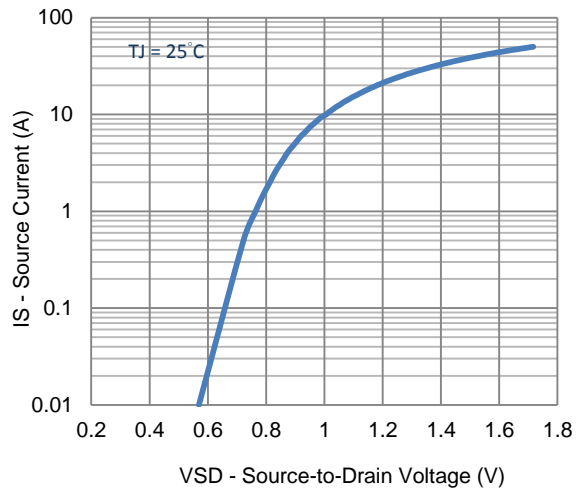
1. On-Resistance vs. Drain Current



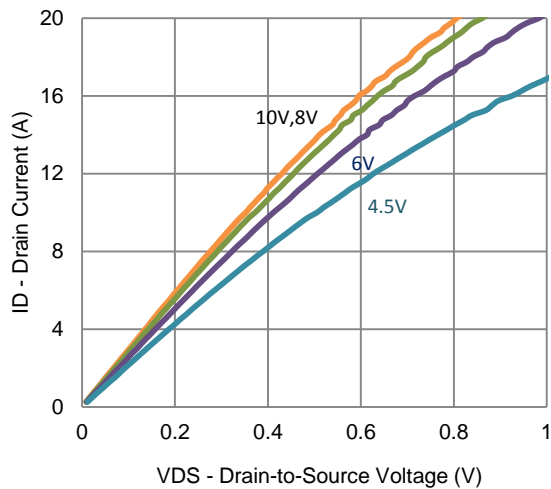
2. Transfer Characteristics



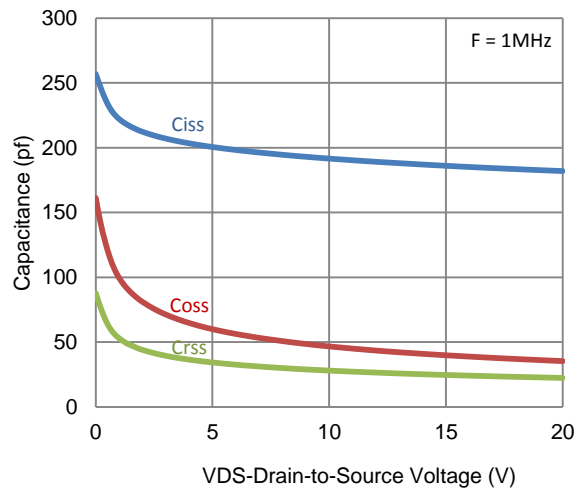
3. On-Resistance vs. Gate-to-Source Voltage



4. Drain-to-Source Forward Voltage

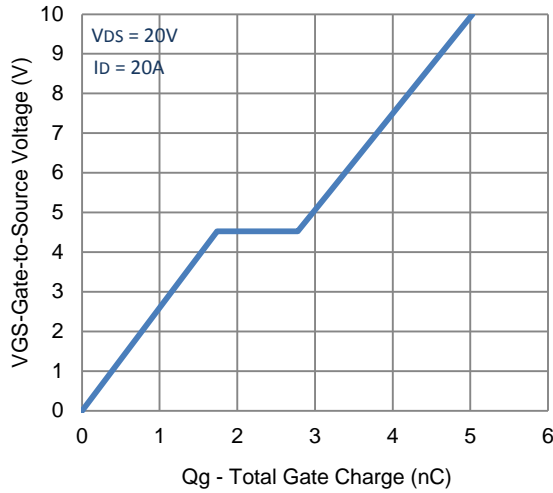


5. Output Characteristics

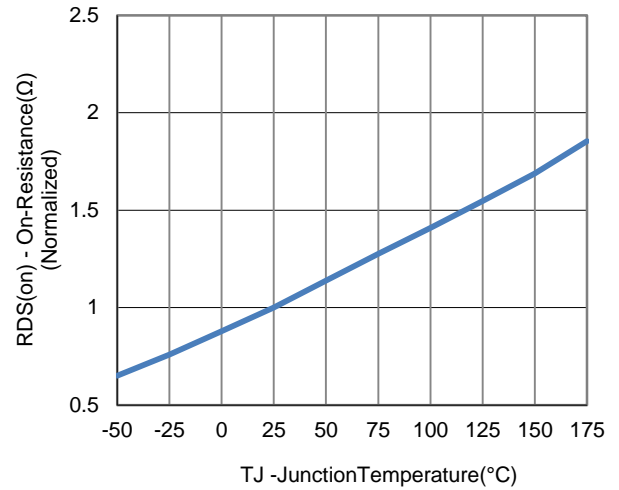


6. Capacitance

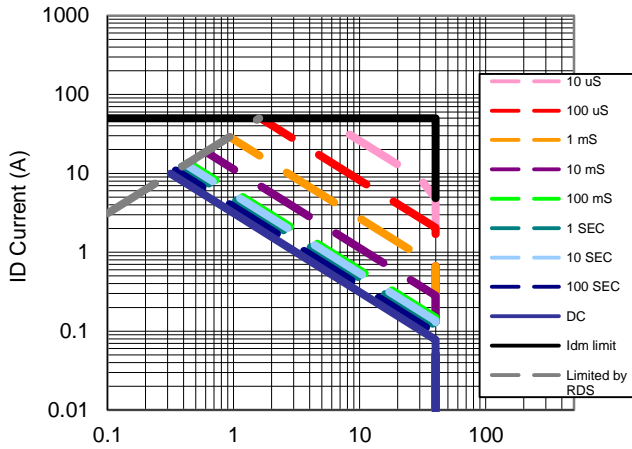
Typical Electrical Characteristics



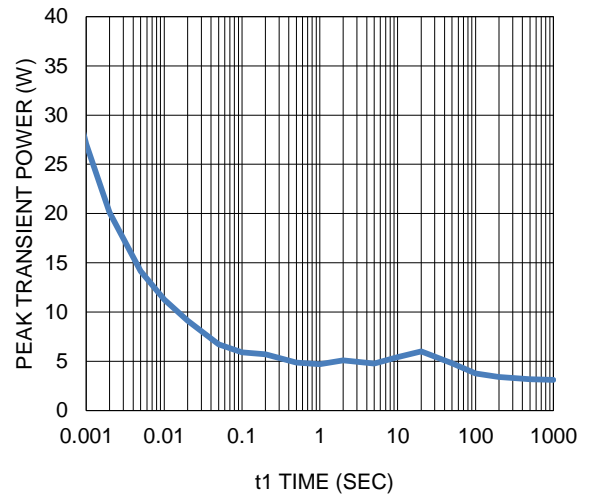
7. Gate Charge



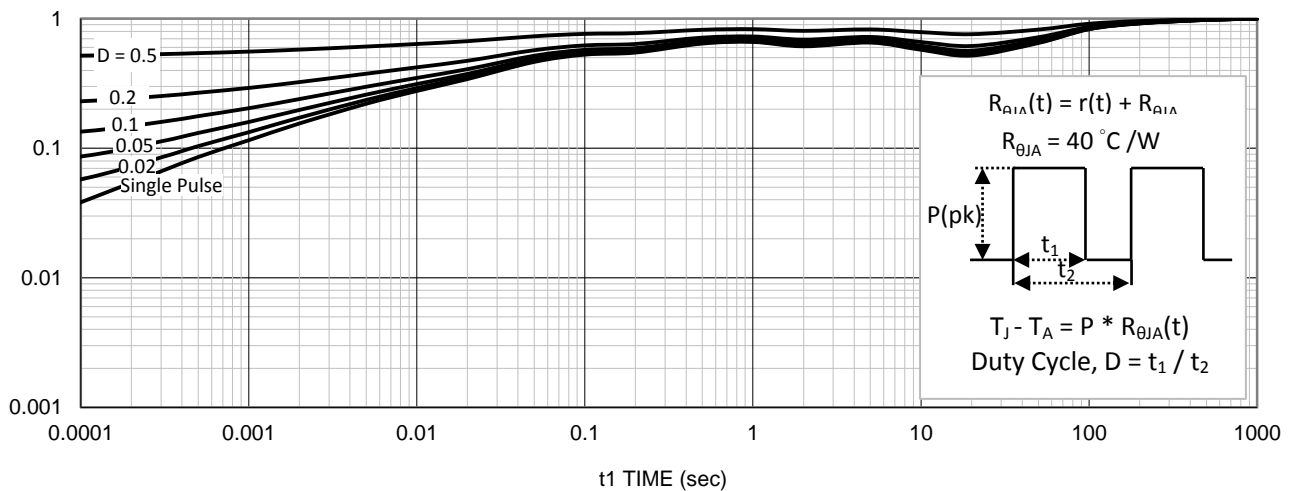
8. Normalized On-Resistance Vs Junction Temperature



9. Safe Operating Area

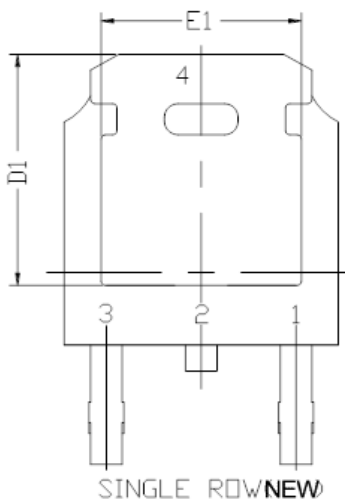
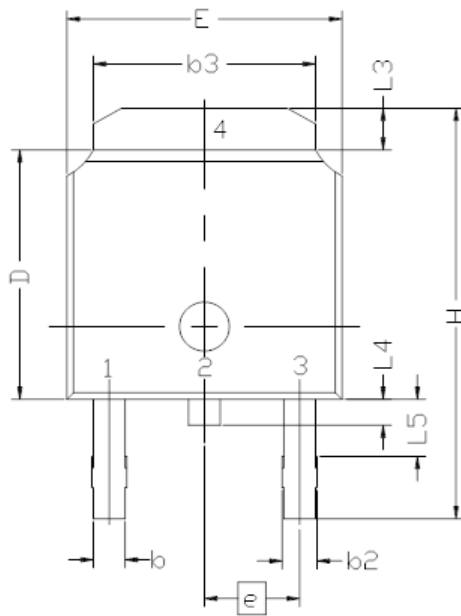


10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

Package Information



| SYMBOL | DIMENSIONAL REQMTS | | |
|--------|--------------------|-------|-------|
| | MIN | NOM | MAX |
| E | 6.40 | 6.60 | 6.731 |
| L | 1.40 | 1.52 | 1.77 |
| L1 | 2.743 REF | | |
| L2 | 0.508 BSC | | |
| L3 | 0.89 | -- | 1.27 |
| L4 | 0.64 | -- | 1.01 |
| L5 | -- | -- | -- |
| D | 6.00 | 6.10 | 6.223 |
| H | 9.40 | 10.00 | 10.40 |
| b | 0.64 | 0.76 | 0.88 |
| b2 | 0.77 | 0.84 | 1.14 |
| b3 | 5.21 | 5.34 | 5.46 |
| e | 2.286 BSC | | |
| A | 2.20 | 2.30 | 2.38 |
| A1 | 0 | -- | 0.127 |
| c | 0.45 | 0.50 | 0.60 |
| c2 | 0.45 | 0.50 | 0.58 |
| D1 | 5.30 | -- | -- |
| E1 | 4.40 | -- | -- |
| θ | 0° | -- | 10° |

Note:

1. All Dimension Are In mm.
2. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
3. Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.